SCLS252I - OCTOBER 1995 - REVISED JANUARY 2000

- EPIC[™] (Enhanced-Performance Implanted CMOS) Process
- Inputs Are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs

description

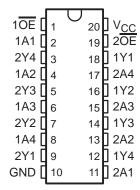
These octal buffers/drivers are designed specifically to improve the performance and density of 3-state memory-address drivers, clock drivers, and bus-oriented receivers and transmitters.

The 'AHCT240 devices are organized as two 4-bit buffers/line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state

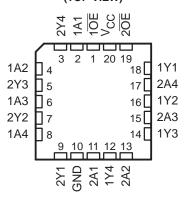
To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHCT240 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AHCT240 is characterized for operation from -40°C to 85°C.

SN54AHCT240 . . . J OR W PACKAGE SN74AHCT240 . . . DB, DGV, DW, N, OR PW PACKAGE (TOP VIEW)



SN54AHCT240 . . . FK PACKAGE (TOP VIEW)



FUNCTION TABLE (each 4-bit buffer/driver)

(00.011		,
INP	UTS	OUTPUT
OE	Α	Υ
L	Н	L
L	L	Н
Н	X	Z



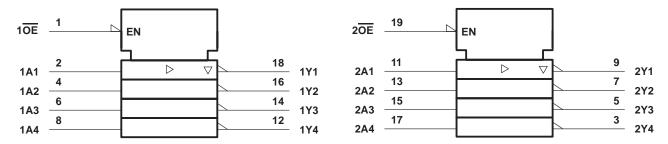
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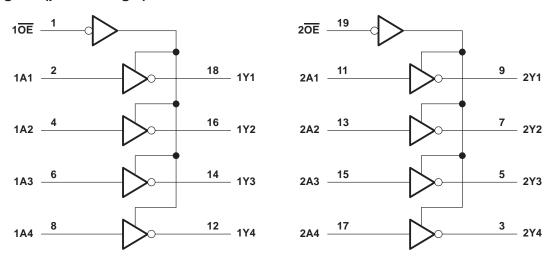
SCLS252I – OCTOBER 1995 – REVISED JANUARY 2000

logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input voltage range, V _I (see Note 1)		0.5 V to 7 V
Output voltage range, VO (see Note 1)		$0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, $I_{IK}(V_I < 0)$		
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CO}	c)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})		
Continuous current through V _{CC} or GND		
Package thermal impedance, θ _{JA} (see Note 2)	: DB package	70°C/W
	DGV package	
	DW package	58°C/W
	N package	69°C/W
	PW package	
Storage temperature range, T _{stg}		–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.



SCLS252I - OCTOBER 1995 - REVISED JANUARY 2000

recommended operating conditions (see Note 3)

		SN54AHCT240		SN74AH	UNIT	
		MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2		2		V
VIL	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	5.5	0	5.5	V
Vo	Output voltage	0	VCC	0	Vcc	V
IOH	High-level output current		-8		-8	mA
l _{OL}	Low-level output current		8		8	mA
TA	Operating free-air temperature	- 55	125	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	VCC	T _A = 25°C			SN54AHCT240		SN74AHCT240		UNIT
PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
V	I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4		4.4		V
VOH	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8		V
Vo.	I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1	V
VOL	I _{OL} = 8 mA	4.5 V			0.36		0.44		0.44	V
loz	V _O = V _{CC} or GND	5.5 V			±0.25		±2.5		±2.5	μΑ
I _I	V _I = V _{CC} or GND	0 V to 5.5 V			±0.1		±1*		±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ
∆I _{CC} †	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5	mA
Ci	V _I = V _{CC} or GND	5 V		2.5	10				10	рF
Со	$V_O = V_{CC}$ or GND	5 V		3						pF



^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$. † This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC} .

SN54AHCT240, SN74AHCT240 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCLS252I – OCTOBER 1995 – REVISED JANUARY 2000

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

DADAMETED	FROM	то	LOAD	T,	λ = 25°C	;	SN54AH	CT240	SN74AH	CT240	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
^t PLH	^	Y	C 15 pF		5.4*	7.4*	1*	8.5*	1	8.5	ns
^t PHL	Α	ī	C _L = 15 pF		5.4*	7.4*	1*	8.5*	1	8.5	115
^t PZH		Y	C _L = 15 pF		7.7*	10.4*	1*	12*	1	12	ns
tPZL	ŌĒ	ī	CL = 15 pr		7.7*	10.4*	1*	12*	1	12	115
^t PHZ	ŌĒ	Y	C: - 15 pE		8.3*	10.4*	1*	12*	1	12	20
t _{PLZ}	OE	ı ı	C _L = 15 pF		8.3*	10.4*	1*	12*	1	12	ns
^t PLH	А	Y	C: 50 pF		5.9	8.4	1	9.5	1	9.5	
t _{PHL}	A	Ť	C _L = 50 pF		5.9	8.4	1	9.5	1	9.5	ns
^t PZH		Y	C _I = 50 pF		8.2	11.4	1	13	1	13	
tPZL	ŌĒ	ī	CL = 50 pr		8.2	11.4	1	13	1	13	ns
^t PHZ	ŌĒ	Y	C ₁ = 50 pF		8.8	11.4	1	13	1	13	ns
t _{PLZ}		ſ	CL = 50 pr		8.8	11.4	1	13	1	13	115
t _{sk(o)}			C _L = 50 pF			1**				1	ns

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, $V_{CC} = 5 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 4)

	PARAMETER H(V) Quiet output, minimum dynamic V _{OH}	PARAMETER				UNIT
	PARAMIETER	MIN	TYP	MAX	UNIT	
VOH(V)	Quiet output, minimum dynamic VOH		4.1		V	
VIH(D)	High-level dynamic input voltage	2			V	
V _{IL(D)}	Low-level dynamic input voltage			0.8	V	

NOTE 4: Characteristics are for surface-mount packages only.

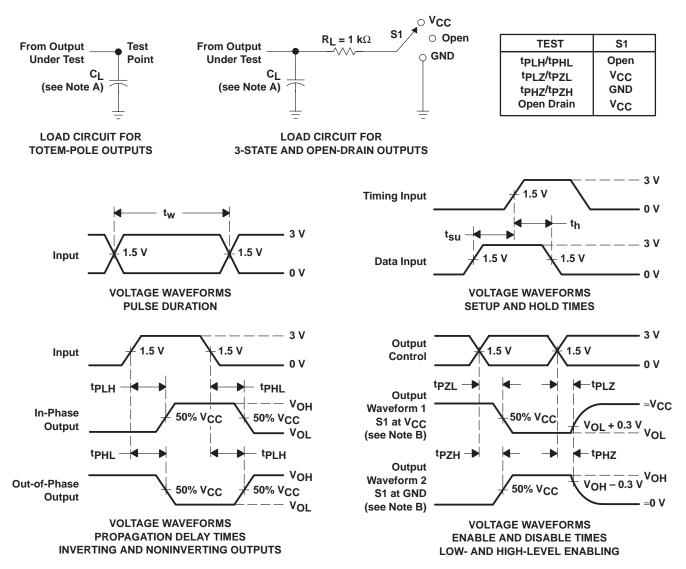
operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
Γ	C _{nd} Power dissipation capacitance	No load, f = 1 MHz	10	pF



^{**} On products compliant to MIL-PRF-38535, this parameter does not apply.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 3 ns, $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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